First Sensor Evaluation Boards Data Sheet
High Voltage Quad Sum and Difference Amplifier
Part Description QP154-Q HVSD
US Order # 10-067
International Order # 5000023

Description
The QP154-Q HVSD is a 1064 nm enhanced quad photodiode array with current-to-voltage amplifiers that provide bottom minus top and left minus right difference signals. Additionally the QP154-Q HVSD provides a signal that is the sum of all four quadrant diode signals. The difference signals are voltage analogs of the light intensity difference sensed by the pairs of photodiode elements in the array. The board has a 7 pin connector attached for easy hook up. Also available without connector.

Applications
- Pulsed 1064 nm laser beam centering
- NIR pulsed light positioning and tracking

RoHS
2011/65/EU

Absolute maximum ratings

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Min</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$T_{STG}$</td>
<td>Storage Temp</td>
<td>-15</td>
<td>+100</td>
<td>°C</td>
</tr>
<tr>
<td>$T_{OP}$</td>
<td>Operating Temp</td>
<td>0</td>
<td>+70</td>
<td>°C</td>
</tr>
<tr>
<td>$V_S$</td>
<td>Power Supply Voltage</td>
<td>±4.5</td>
<td>±18</td>
<td>V</td>
</tr>
<tr>
<td>$V_A$</td>
<td>Applied Bias Voltage*</td>
<td>30</td>
<td>50</td>
<td>V</td>
</tr>
</tbody>
</table>

Electro-optical characteristics @ 23°C

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Characteristics</th>
<th>Test conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_O$</td>
<td>Output Voltage (all outputs)</td>
<td>$V_p = ± 15 V; V_A = 50 V$</td>
<td>---</td>
<td>---</td>
<td>---</td>
<td>V</td>
</tr>
<tr>
<td>$I_O$</td>
<td>Output Current limit</td>
<td>$V_p = ± 15 V; V_A = 50 V$</td>
<td>---</td>
<td>---</td>
<td>25</td>
<td>mA</td>
</tr>
<tr>
<td></td>
<td>Slew Rate</td>
<td>$V_p = ± 15 V; V_A = 50 V$</td>
<td>---</td>
<td>---</td>
<td>10</td>
<td>V/μs</td>
</tr>
<tr>
<td></td>
<td>Theoretical Noise</td>
<td>$V_p = ± 15 V; V_A = 50 V$</td>
<td>---</td>
<td>15</td>
<td>---</td>
<td>nV/Hz</td>
</tr>
<tr>
<td>$Δf_{3dB}$</td>
<td>Bandwidth**</td>
<td>$V_p = ± 15 V; V_A = 50 V; λ = 1.06 μm$</td>
<td>---</td>
<td>150</td>
<td>---</td>
<td>kHz</td>
</tr>
</tbody>
</table>

* do not apply negative voltages to pad 1.
** dependant on bias voltage

Spectral response @ 23°C

Connections

Active area: 4 x 38.5mm² (14.0 mm DIA w/ 70 µm GAPS)
The QP154-Q HVSD outputs are labeled as B-T for bottom minus top, L-R for left minus right. The output voltages are obtained by routing the diode element currents into current-to-voltage amplifiers with a gain of $10^4$:

\[
V_{B-T} = [(I_{1,2}) - (I_{1,4})] \cdot (10^4) \text{ on Pad 2.}
\]

\[
V_{L-R} = [(I_{2,3}) - (I_{1,4})] \cdot (10^4) \text{ on Pad 3.}
\]

\[
V_{SUM} = [(I_{1,2}) + (I_{2,3}) + (I_{3,4})] \cdot (10^4) \text{ on Pad 4.}
\]

$I_{X,Y}$ is the sum of the currents generated by photodiode elements $x$ and $y$. Looking down through the window of the photodiode, the quadrants are identified in drawing on page one.

**APPLICATION NOTES**

**Beam Size**

The light spot applied to the QP154-Q HVSD must be smaller than the diameter of the quadrant photodiode array. The detector active area has a diameter of 14 millimeters. If the light spot is too large, it may be reduced to fit the photodiode array by use of a lens. A decrease in output signal strength is observed as the light spot crosses the separation boundary of the quadrants, usually referred to as the "gap". This effect is more pronounced as the diameter of the light spot decreases, as a larger percentage of the light spot's power falls within the non-active gap. For this reason, the minimum light beam diameter should be at least 1 millimeter. A lens may be used to increase the beam diameter.

**Photodiode Bias Operation**

The QP154-Q HVSD array must be operated in the reverse bias mode. The device will not operate correctly without a reverse bias applied to Pin 1. The minimum recommended reverse bias is 30 volts. Do not connect Pin 1 to negative voltages, as this will forward bias the photodiode array, making it inoperable and possibly damaging the circuit.

**Use of Sum and Difference Signals for Alignment**

The sum output signal may be used to help preliminary alignment of the QP154-Q HVSD to the source light beam. First, the beam or the QP154-Q HVSD is adjusted for maximum sum output signal. Second, the beam or QP154-Q HVSD is adjusted until the L-R and B-T signals are at minimum. This procedure results in the beam being centered on the quad photodiode array.

**Signal Null Detector for Servo Applications**

A common application for the QP154-Q HVSD is a signal null detector as part of a servo system that maintains the position of a light beam. Errors in beam position are reported by the QP154-Q HVSD and may be used to adjust a positioning device that restores the beam or the beam's source to a null position.

**Speed of Response**

Increasing the photodiode bias voltage will increase the speed of the QP154-Q HVSD. As noted above, Pin 1 must supply a positive bias voltage to the quad for basic operation and improved frequency response at longer wavelengths (e.g. 1.06 µm) of illumination. Care should be taken not to exceed the breakdown voltage of the quad photodiode. See Absolute Maximum Ratings on page one for maximum values.

**Temperature Considerations**

The operation temperature must be between 0 and 70 °C. For best resolution the temperature should be kept at or below 25 °C. Thermal gradients across the detector will cause position errors and should be avoided.

**Offsets**

Precision components are used in the circuitry but as much as 30 millivolts of offset may still be present in the outputs. If this causes a problem the offsets should be removed externally.